

REJ03G0690-0300 (Previous ADE-208-1056) Rev.3.00 Mar 03, 2006

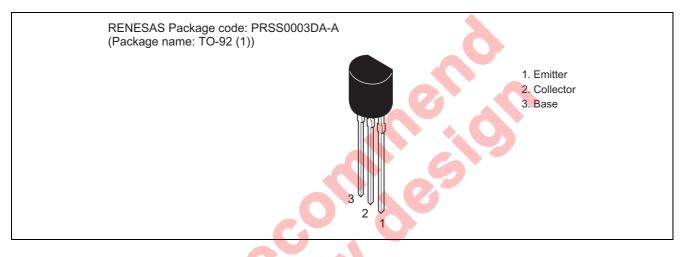
2500

### Application

### • Low frequency low noise amplifier

• Complementary pair with 2SA872A

### Outline



# Absolute Maximum Ratings

			$(1a = 25^{\circ}C)$
Item	Symbol	Rating	Unit
Collector to base voltage	V <sub>CBO</sub>	120	V
Collector to emitter voltage	V <sub>CEO</sub>	120	V
Emitter to base voltage	V <sub>EBO</sub>	5	V
Collector current	Ι <sub>C</sub>	50	mA
Collector power dissipation	Pc	300	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-50 to +150	°C



### **Electrical Characteristics**

(Ta	=	25°	C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Collector to emitter breakdown voltage	V <sub>(BR)CEO</sub>	120	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$	
Collector cutoff current	I <sub>CBO</sub>	_		0.5	μA	$V_{CB} = 100 \text{ V}, I_E = 0$	
DC current transfer ratio	$h_{FE1}*^1$	400	—	1200		$V_{CE} = 12 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	
	h <sub>FE2</sub>	160	_	—		$V_{CE} = 12 \text{ V}, I_C = 0.1 \text{ mA}$	
Base to emitter voltage	$V_{BE}$		_	0.75	V	$V_{CE} = 12 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$		—	0.5	V	$I_{C} = 10 \text{ mA}, I_{B} = 1 \text{ mA}$	
Gain bandwidth product	f⊤	_	200	—	MHz	$V_{CE} = 12 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$	
Collector output capacitance	Cob	_	1.6	—	pF	$V_{CB} = 25 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	
Noise figure	NF	_	—	5.0	dB	$V_{CE} = 6 V, I_C = 50 \mu A, f = 10 Hz$	
		_	—	1.5	dB	$R_g = 50 \text{ k}\Omega$ f = 1 kHz	

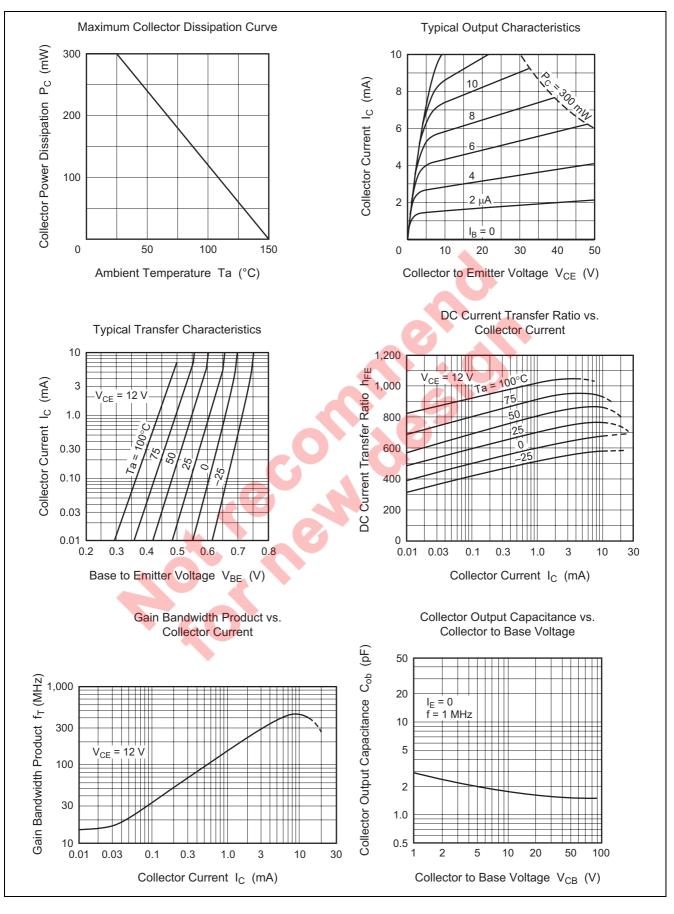
Note: 1. The 2SC1775A is grouped by  $h_{FE1}$  as follows. 

E	F	
400 to 800	600 to 1200	

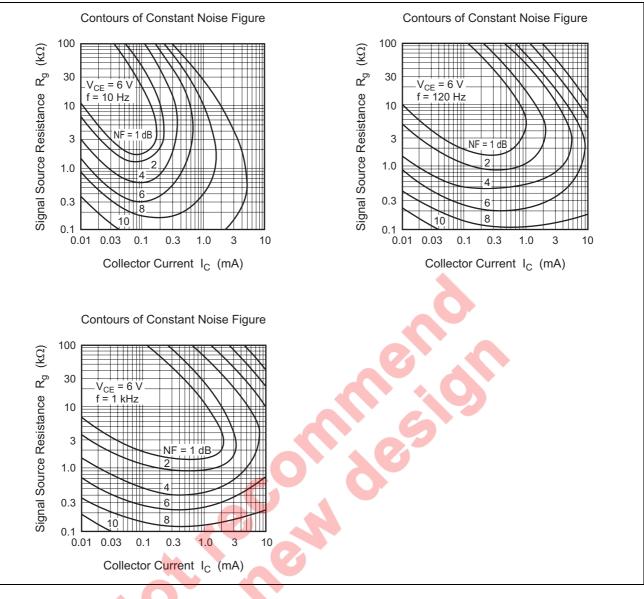
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### **Main Characteristics**



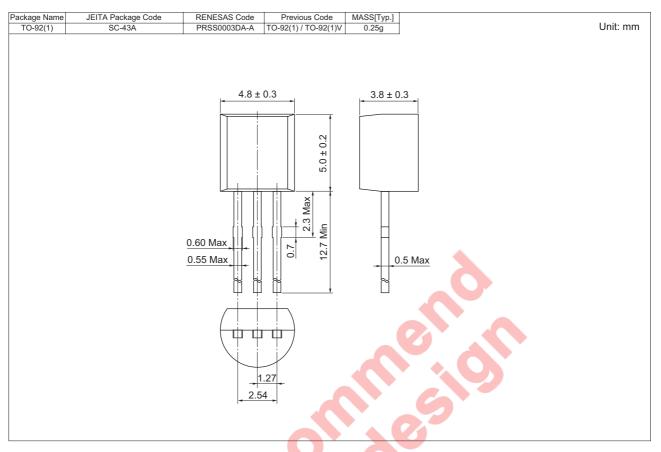








### **Package Dimensions**



### **Ordering Information**

Part Name		Quantity			Shipping Container	
2SC1775AETZ	2500		0	Hold Box, I	Radial Taping	
2SC1775AFTZ						

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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